# **MOSFET** - Power, Single P-Channel, SOT-23

-60 V, 230 mΩ, -1.1 A

# NVR5124PL

## Features

- Trench Technology
- NVR Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

#### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V <sub>DSS</sub>	-60	V
Gate-to-Source Voltage			V <sub>GS</sub>	±20	V
Continuous Drain	Steady State	T <sub>A</sub> = 25°C	۱ <sub>D</sub>	-1.1	А
Current R <sub>θJA</sub> (Notes 1, 2, 3)		T <sub>A</sub> = 100°C		-0.67	
Power Dissipation $R_{\theta JA}$ (Notes 1, 2)		T <sub>A</sub> = 25°C	PD	-0.47	W
		T <sub>A</sub> = 100°C		0.19	
Pulsed Drain Current	T <sub>A</sub> = 25	°C, t <sub>p</sub> = 10 μs	I <sub>DM</sub>	25	А
Operating Junction and Storage Temperature Range			T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C
Source Current (Body Diode)			۱ <sub>S</sub>	-0.6	А
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL RESISTANCE MAXIMUM RATINGS (Note 1)

Parameter	Symbol	Value	Unit
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	268	°C/W

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

- 2. Surface-mounted on FR4 board using a 650  $\rm mm^2,$  2 oz. Cu pad.
- 3. Continuous DC current rating. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

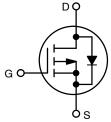


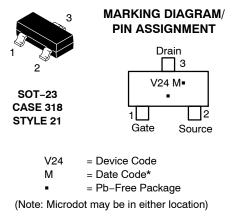
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V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> MAX	I <sub>D</sub> MAX		
–60 V	230 m $\Omega$ @ –10 V	-1.1 A		
-00 V	365 mΩ @ −4.5 V	-1.1 A		







\*Date Code orientation may vary depending upon manufacturing location.

#### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NVR5124PLT1G	SOT–23 (Pb–Free)	3000 / Tape & Reel

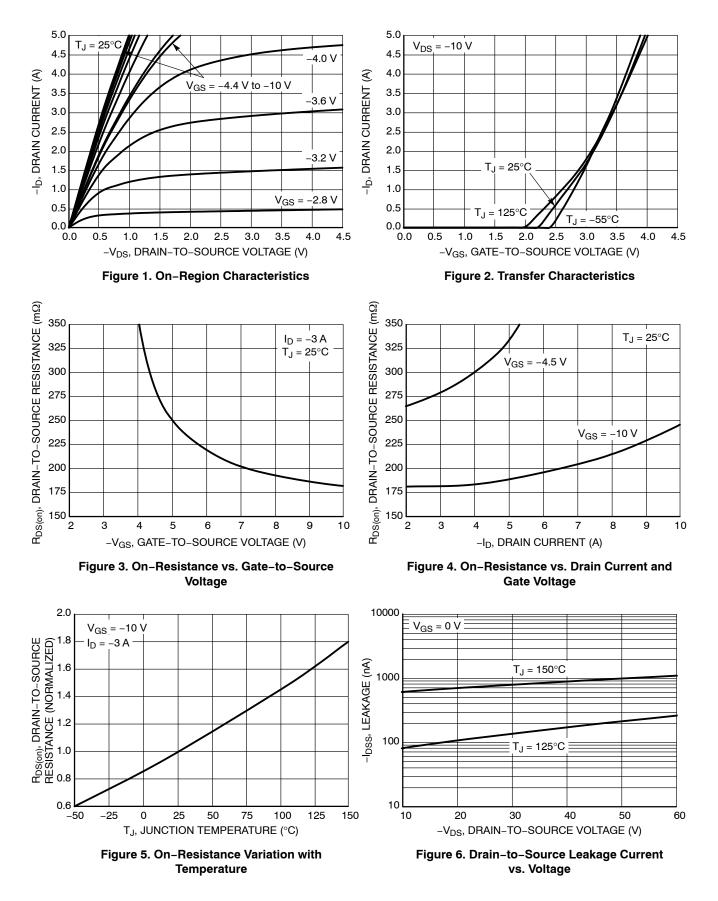
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C unless otherwise noted)

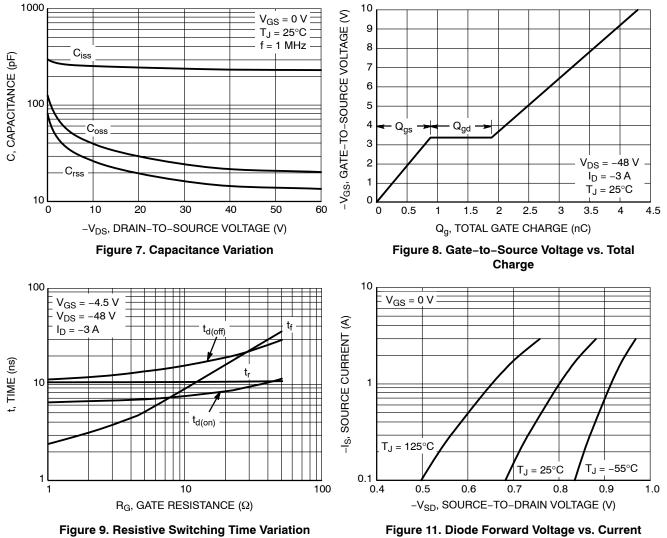
Parameter	Symbol	Test Condition		Min	Тур	Мах	Uni
OFF CHARACTERISTICS	J					-	-
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ = 0 V, I <sub>D</sub> =	–250 μA	-60			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V,	T <sub>J</sub> = 25°C			-1.0	μA
		$V_{\rm DS} = -60  \rm V$	T <sub>J</sub> = 125°C			-10	
Gate-to-Source Leakage Current	I <sub>GSS</sub>	$V_{DS}$ = 0 V, $V_{GS}$	= ±20 V			±100	nA
ON CHARACTERISTICS (Note 4)							-
Gate Threshold Voltage	V <sub>GS(TH)</sub>	$V_{GS} = V_{DS}, I_D =$	= –250 μA	-1.5		-2.5	V
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10 V, I	<sub>D</sub> = -3 A		183	230	mΩ
		V <sub>GS</sub> = -4.5 V,	<sub>D</sub> = -3 A		280	365	1
Forward Transconductance	9 <sub>FS</sub>	V <sub>DS</sub> = -15 V, I	<sub>D</sub> = -5 A	4			S
CHARGES AND CAPACITANCES							
Input Capacitance	C <sub>iss</sub>				240		
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V, f = 1.0 MHz, V <sub>DS</sub> = -25 V			27.6		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	•DS = 2			18.5		
Total Gate Charge	Q <sub>G(TOT)</sub>				2.3		
Threshold Gate Charge	Q <sub>G(TH)</sub>	$V_{GS} = -4.5 \text{ V}, V_{DS} = -48 \text{ V},$ $I_D = -3 \text{ A}$ $V_{GS} = -10 \text{ V}, V_{DS} = -48 \text{ V},$ $I_D = -3 \text{ A}$			0.5		nC
Gate-to-Source Charge	Q <sub>GS</sub>				0.9		
Gate-to-Drain Charge	Q <sub>GD</sub>				1.0		
Total Gate Charge	Q <sub>G(TOT)</sub>				4.3		
SWITCHING CHARACTERISTICS (No	te 5)						
Turn-On Delay Time	t <sub>d(on)</sub>				6.6		
Rise Time	t <sub>r</sub>	$V_{GS}$ = -4.5 V, $V_{D}$	s = -48 V.		10.6		ns
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_{\rm D} = -3 \rm{A},  R_{\rm G}$	= 2.5 Ω		12.2		
Fall Time	t <sub>f</sub>				3.5		1
DRAIN-SOURCE DIODE CHARACTER	ISTICS				-	-	-
Forward Diode Voltage	V <sub>SD</sub>	$V_{GS} = 0 V,$ $I_{S} = -3 A$	$T_J = 25^{\circ}C$		-0.88	-1.0	V
		I <sub>S</sub> = -3 A	T <sub>J</sub> = 125°C		-0.76		
Reverse Recovery Time	t <sub>RR</sub>	$V_{GS} = 0 \text{ V},$ $dI_S/dt = 100 \text{ A}/\mu\text{s},$ $I_S = -3 \text{ A}$			15		ns
Charge Time	ta				13		
Discharge Time	t <sub>b</sub>				2.4		
Reverse Recovery Charge	Q <sub>RR</sub>				10		nC

Product parametric performance is indicated in the Electrical Characteristics for the instead test conditions, performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2%. 5. Switching characteristics are independent of operating junction temperatures.

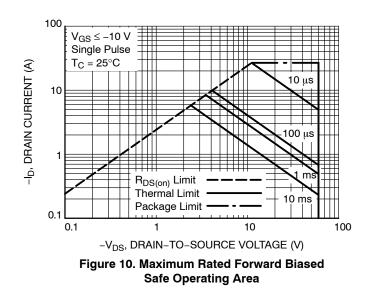
#### **TYPICAL CHARACTERISTICS**



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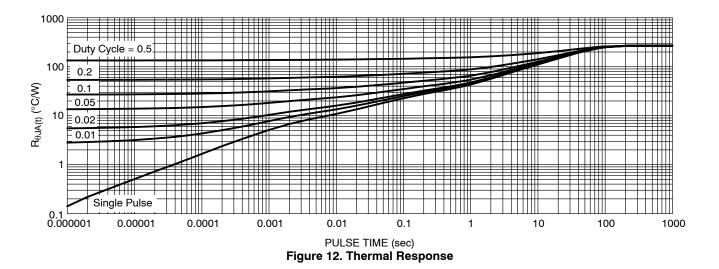


vs. Gate Resistance

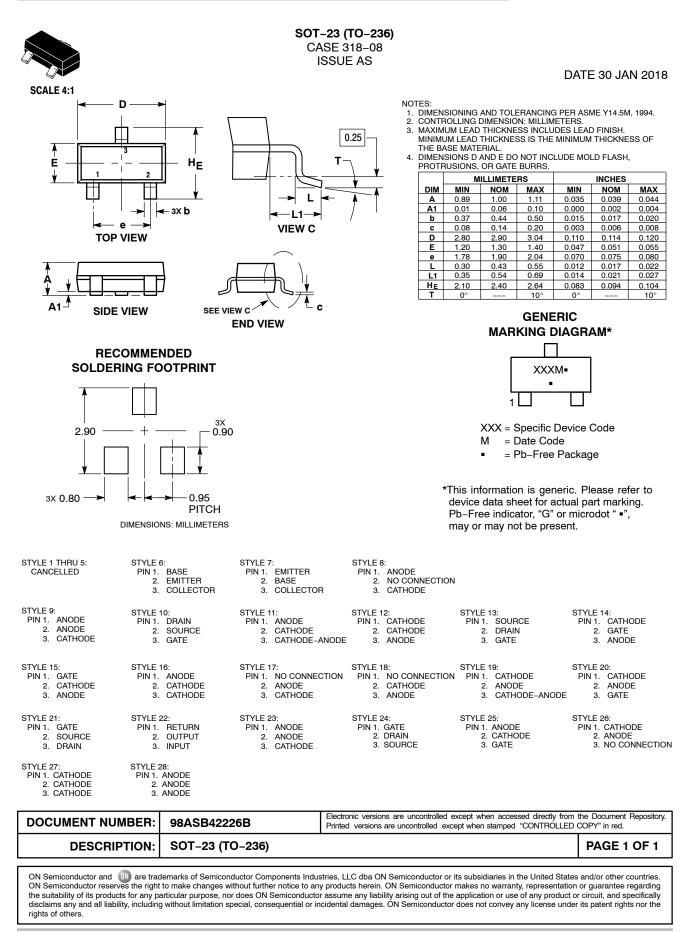


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#### **TYPICAL CHARACTERISTICS**







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